

In the Specification

On page 1, insert at line 7, please delete the "CROSS-REFERENCE TO RELATED PATENT APPLICATIONS" section and insert therefore the following. Attached hereto is a marked-up version of the changes made to the specification and claims by the current amendment. The attached page is captioned "Version with markings to show changes made."

CROSS-REFERENCE TO RELATED PATENT APPLICATIONS

B1  
This application is a continuation application of U.S. patent application, serial no. 09/100,384, now U.S. Patent No. 6,365,924, entitled "A Dual-Direction Over-Voltage And Over-current IC Protection Device and Its Cell Structure," by Wang et al, assigned to National Semiconductor Corporation, which is also the Assignee of the present application.

In the Claims

Please amend Claims 2, 3, 5-8 and 10 as follows. Attached hereto is a marked-up version of the changes made to the claims by the current amendment. The attached page is captioned "Version with markings to show changes made." Please cancel Claims 1 and 9. Please add new Claims 21-30. Below is a list of all the now pending claims.

1. (Cancelled)

2. (Amended) The ESD protection structure of Claim 8, wherein said first conductivity type is an n-type semiconductor and said second conductivity type is a p-type semiconductor.

3. (Amended) The ESD structure of Claim 8, wherein said first conductivity type is a p-type semiconductor and said second conductivity type is an n-type semiconductor.

4. (Cancelled)

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